SERVICE MANUAL

model 115B



TABLE OF CONTENTS

SEC	TION	PAGI
Intro	duction	. 1
ΑM	Tuner	. 1
	Tuner	-
	Alignment Procedure	-
	Alignment Procedure	_
	Equipment Required for Servicing	_
	s List	
Tech	nnical Specification	. 25
	LIST OF ILLUSTRATIONS	
FIG	URE	PAGE
1.	Block Diagram of the HA1156	. 4
2.	Dial Stringing	. 6
3.	Front Panel Adjustment and Component Locations	
4.	Main Chassis Component Locations (Top View)	
5.	Rear Panel Adjustment and Component Locations	. 8
6.	Main Chassis Component Locations (Bottom View)	
7.	FM Front End Assembly P100 Component Locations	
8.	AM Tuner Unit Assembly P150 Component Locations	
9.	FM IF Amplifier Assembly P200 Component Locations	. 10
10.	FM MPX Stereo Decoding and Noise DC Amplifier Assembly	
	P300 Component Locations	
11.	Power Supply Unit Assembly P400 Component Locations	. 11
12.	Selector Push Switch Assembly PS01 Component Locations	12
13.	Mono Push Switch Assembly PT01 Component Locations	
14.	Schematic Diagram	13, 14
15.	Exploded Mechanical Diagram	15, 16
TAB	SLE	PAGE
1.	Test Equipment Required for Servicing	6

1. INTRODUCTION

This service manual was prepared for use by Authorized Warranty Stations and contains service information for Marantz Model 115B Stereophonic Tuner.

Servicing information and voltage data included in this manual are intended for use by the knowledgeable and experienced technician only. All instruction should be read carefully. No attempt should be made to proceed without a good understanding of the operation in the receiver.

The parts list furnish information by which replacement part may be ordered from the Marantz Company. A simple description is included for parts which can be usually be obtained through local suppliers.

The Model 115B is a tuner version of the Marantz's Model 4270 Tuner/Amplifier and almost the same circuitry as used in the Model 4270 is employed except the audio Amplifier, and power supply circuit.

2. AM TUNER

The AM TUNER portion of the 115B is composed of one IC circuit (including RF amplifier, local oscillator, mixer, IF amplifier, detector, and a signal strength indicator amplifier) and one transistor amplifier to amplify the detected audio signals.

All components except Tuning capacitor and ferrite bar antenna are mounted on a printed circuit board P150.

The AM signals induced in a ferrite bar antenna are applied to the input of RF amplifier (Pin ①) through a capacitor of C151 and amplified to the level required for overcoming the conversion noises, thus giving good S/N performance. The tuned circuits inserted in both output and input circuit of RF amplifier assure very high image and spurious rejection performance.

Thus amplified and selected AM signals are then applied to one input of Mixer section (Pin®) through a coupling capacitor C158. While the local oscillator voltage is injected to the other input of the section (Pin®) through a capacitor C157. Then both AM signals and oscillating voltage are mixed and converted into 455KHz intermediate frequency. The resulting IF signal is applied to the first IF transformer L153 consisting of one ceramic filter and two tuned circuits.

The output of L153 is led to the IF amplifier's input (Pin①) through a coupling capacitor C169' and amplified to the sufficient level to drive the detector. The output of IF amplifier (Pin ®) is led to the detector's input (Pin ®) through IF filter L154. The detected audio signal derived from pin—is filtered and amplified and final audio output is obtained from the collector of H152 and applied to the output jacks through the function switch and OUTPUT LEVEL controler R005 and output amplifier H401 and H402.

The DC component of the detected IF signal is used as a AGC voltage to control emitter current of RF and IF amplifier through the resistor R154 and R155. A part of the DC component is also applied to the signal strength indication amplifier incorporated in the IC. The output appears at pin (4) and is level adjusted by R152, indicated on the signal strength meter M002.

2.1 Suggestions for AM Tuner trouble shooting

Check for broken AM bar antenna, next try to tune station by rotating fly-wheel tuning knob slowly and observe the AM signal strength meter whether it deflects or not. If the signal strength meter gives a deflection at several frequencies received, no failure may exist in the stages at least preceding final IF transformer L154. Next connect a oscilloscope to the test point ® or J157 and check for audio signals with the tuning meter deflected. If the signal strength meter does not deflect, check the local oscillator circuit. Normal oscillating voltage at the hot end of the oscillator tuning capacitor is about 1.5 or 3 volts, varying with tuning capacitor position. When measuring oscillating voltage use a RF VTVM, no circuit tester gives correct indication. If the local oscillator voltage is normal, check all voltage distribution in the AM circuits by using a DC VTVM and compare the measured values with those given in the schematic diagram.

3. FM TUNER

The FM Tuner section of Model 115B is divided into four functional blocks: FM Front End, IF Amplifier and Detector, Muting Control and MPX Stereo Decoding Circuit.

FM signals induced by a FM antenna are led to FM antenna coil L101 through an attenuator switch and a balun coil. These signals are then applied to the FET RF amplifier which in turn applies its output to the next FET Mixer H102 through the double tuned high selective circuits. The FET Mixer convert its input signal into 10.7MHz intermediate frequency and amplifies it at the same time. The H103 is a local oscillator and its output is injected into the source of the FET Mixer, the injection voltage is about 700mV. The 10.7MHz front end output is led to the next IF amplifier unit through a coaxial cable.

The IF amplifier unit consists of five stages of IF amplifier and one stage of AGC amplifier. Three pieces of dual elements ceramic filters are also used to obtain high selectivity, four stages of symmetrical diode limiters are also employed for the best limiting characteristics, improved capture ratio and good AM suppression.

A part of FM Front End output is applied to the AGC amplifier H201 and rectified its outupt is fed back to the gate of FET RF amplifier to decrease the gain with increased signal strength.

The IF signal sufficiently amplified through every stage of IF amplifier is finally applied to the detector amplifier. The detected audio output is led to the buffer amplifier H208 and its buffered output is led to; (a) noise amplifier H310 through resistor R378 and capacitor C333, (b) Quadradial Jack on the rear panel through resistor R379, (c) MPX stereo decoding IC (H321) through R301 and H301.

3.1 Audio Muting and Stereo mode auto-selecting circuit

The muting circuit consisting of all solid-state electrical switching has been incorporated in the Model 115B. Three inputs control the muting function. The first is related to signal strength, the second to the noise condition at the detector and the third is derived from the DC component of the detector output. These inputs are properly matrixed and gated to provide muting free from noise and transients.

The first input of DC voltage obtained by rectifying a part of IF output signal from the H205 and H206 is applied to the base of H308 and turns on it, if the IF output is greater than predetermined level (muting threshold level). When the H308 is turned on the H309 is turned off, allowing the emitter-collector resistance increasing and the collector voltage rises about 9V. The increased collector voltage increases the gate bias voltage and turns on the switching FET H301, decreasing the source-drain resistance to near zero ohm and allowing the audio signal applied to the source to flow to the pin ② of decoding IC through the source-drain path.

When the input signal is lower than predetermined level, the DC output obtained is small and can not turn on the H308, thus the H308 keeps its turn-off stage and this makes H309 turn on, decreasing the collector voltage and turning off H301. Thus no audio signals can pass through the FET. This is the fundamental principle of the muting operation but for more elaborate muting operation the second and the third inputs are necessary.

The second input is used to protect the muting operation and MPX stereo beacon lamps from misoperation due to undesirable noises. The high frequency noises included in the detected audio signals are separated by a small capacitor C333 and amplified by the noise amplifier transistor H310 and its output is rectified by the two diodes. The rectified DC output is proportional to the noise components in the audio signals.

When there are excessive noises in the audio signals such as obtained with a station incorrectly tuned in, the rectified DC output turns on the transistor H311, decreasing the emitter-collector resistance to zero. This means the collector of H309 is short-circuited to the ground, therefore the H301 is turned off and any audio signals having excessive high frequency noises can not go through the FET's source-drain path.

The transistor H317 also turns off when the transistor H309 or H311 turns on, and makes the transistor H303 turn on, which is connected to pin ® on the MPX decoding IC. Therefore, pin

(8) is equivalently grounded, and the operation of the IC becomes monaural. This permits misoperation of stereo due to undesirable noises during deviation of tuning.

The third input is obtained from the FM discriminator circuit. The DC output so called "S" curve is applied to the gate of H312 through a resistor R273 and deviding network (R361 & R362). The DC output is zero with a station correctly tuned in, but will vary from negative to positive values or vice versa when the tuning point is deviated toward either plus or minus frequency from the correct tuning frequency.

When the DC output is increased to a greater level than that of predetermined, the increased source potential of H312 makes the transistor H315 turn on (this means the collector of H309 is short-circuited to the ground), ... H301 turn off, ... H317 turn off, ... H303 turn on, this means the MPX Stereo Decoding IC is grounded at pin (§) and operates in the monaural mode of operation, and the stereo indicator lamp does not light. When the DC output is increased to the negative predetermined level, the decreased source potential turns off the H313 which in turn makes the H314 turn on (this means the collector of H309 is short-circuited to the ground). The subsequent changes are exactly the same as that just described above.

Thus when the tuning is shifted or deviated to the certain frequencies in which undesirable noisy side-audio signals are produced, both muting and monaural/stereo Switching Transistor H303 are operated automatically and open the circuits.

With the station correctly tuned in, the bias current of the FET H312 is adjusted so that both transistor H314 and H315 are not turned on, giving no effect on the transistor H308.

3.2 MPX Stereo Decoding Circuit

The stereo composite signal from the buffer amplifier undergoes a phase compensation by R301 and C301, is applied through the muting switching FET H301 to the input terminal pin (2), of the MPX stereo decoding IC H321 on a PLL (Phase Locked Loop) basis, and decoded into the left and right stereo signals, which become available at pins 4 and 5 respectively. These decoded left and right stereo audio signals are introduced through a low pass filter composed of L301 to L304 and C311 to C320 for elimination of undesirable residual switching signal and through a de-emphasis network consisting of R325, R326, C321 and C322, into the npn-pnp direct coupled audio amplifier, where the signals are amplified to a required level for the output from J311 and J313. From these jacks, the audio signals are further led through the function switch and OUTPUT LEVEL control R005 into the output amplifiers H401 and H402, where the signals are amplified to be fed to the output terminals. Figure 1 presents an internal block diagram showing the functions of the PLL basis MPX stereo decoding IC HA1156. The input stereo composite signal, amplified by the audio amplifier, is delivered to the phase detectors PD-1 and PD-2. A part of the stereo composite signal is also applied to the stereo decoder section. The VCO (Voltage Control Oscillator) produces a free run oscillation in the neighborhood of 76KHz with the time constant determined by a capacitor C305 and resistors R311 and R312 set on the outside of pin (4). The VCO output has its frequency divided into 19KHz through the two stages of the frequency divider (DIV-1 & DIV-2), and is reverted to the phase detector PD-1, which contains two input terminals designed to produce an output in proportion to the product of the two input signals. The signal applied to one of the inputs of PD-1 is the 19KHz square wave formed through frequency division of the 76KHz VCO output signal by the two stages of the frequency divider DIV-1 and DIV-2, and the 19KHz pilot signal included in the stereo composite signal as a reference signal is applied to the other input. Therefore, the output of PD-1 which has passed through the low pass filter LPF-1 provides DC output voltage in proportion to the phase variance between the two inputs. This DC output voltage is amplified by the DC amplifier, and supplied to the 76KHz VCO as a control voltage. This means that the output frequency and phase of the VCO have been phase-locked to the input pilot signal. The 38KHz sub-carrier reproduced by PLL as stated above is delivered through the stereo switch to the stereo decoder section as a switching signal, thus driving the decoder section. One of the inputs of PD-2 is given the 19KHz resulting from the frequency division completed by DIV-1 and DIV-3. whereas the other input gets the 19KHz output contained in the composite signal, and the output is provided with a DC output in proportion to the amplitude of the pilot signal. This DC output is furnished through LPF-2 to the trigger amplifier which drives the stereo indicator lamp and stereo switch. Therefore, insufficient supply of the pilot signal results in failure to light the stereo indicator and to turn on the stereo switch located in the path of the 38KHz switching signal, thereby avoiding a wrong stereo operation. H303 attached on the outside of pin (8) is a switching transistor for automatic monaural-stereo switchover. When the intensity of an incoming signal from an FM station is weaker than a predetermined level, this H303 is turned on and pin (8) is grounded, thereby developing a condition for monaural reception. For a forced monaural operation, switch the MODE switch to "MONO," and H303 comes into an "On" condition with the positive bias voltage applied to the base, and pin (8) is grounded, thereby establishing monaural opeartion. The transistor H302 connected externally to pin (4) is intended to stop the 76KHz oscillation of the VCO which interferes an AM signal during the reception of an AM station. When the function switch is set to "AM" position, a positive bias is charged on the base of H302, H302 is turned on, and pin (4) is grounded. Thus, the oscillation of the VCO is stopped, ending the interference with AM reception.

3.3 Suggestion for Trouble Shooting of FM Tuner

3.3.1 Symptom: No FM Reception

First turn on the Power switch and try to tune FM stations. Rotate the fly-wheel tuning knob slowly and observe the FM signal strength meter. If the signal strength meter deflect at several frequencies received, the tuner circuits preceding the discriminator circuit may have no failure. When no reading is obtained in the meter, check FM local oscillator circuit, using a RF VTVM. The normal local oscillator voltage is one or two volts (rms) at the tuning capacitor, depending on the tuning capacitor position. If the local oscillator voltage is normal, next check all voltage distribution in the FM Front End and IF amplifier unit and compare them with those shown in the circuit diagram. When signal strength meter deflects but no sound is obtained, check audio circuit, using high sensitive oscilloscope.

3.3.2 Symptom: No Stereo Separation

First check the "MONO" switch is in normal out position. Connect a FM RF signal generator output modulated by a stereo modulator to the rear FM antenna terminals, and check the stereo beacon is turned on or not. If not turned on, check for 19KHz VCO output signal (J310), using an oscilloscope and a frequency counter.

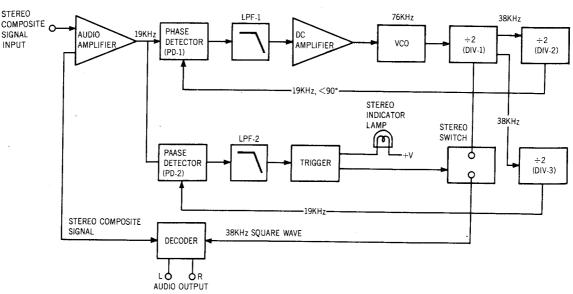


Figure 1. Block Diagram of the HA1156

4. AM ALIGNMENT PROCEDURE

4.1 AM IF Alignment

- 1. Connect a sweep generator to the J153 and an alignment scope to the test point (B).
- 2. Rotate each core of IF transformer L153 and L154 for maximum height and flat top symmetrical response.

4.2 AM Frequency Range and Tracking Alignment

- 1. Set AM signal generator to 525KHz. Turn the tuning capacitor fully closed (place the tuning pointer at the low end.) and adjust the oscillator coil L152 for maximum audio output.
- 2. Set the signal generator to 1650KHz. Place the tuning pointer in the high frequency end and adjust the oscillator trimmer on the oscillator tuning capacitor for maximum audio output.
- 3. Repeat the step 1 and 2 until no further adjustment is necessary.
- 4. Set the generator to 600KHz and tune the receiver to the same frequency and adjust a slug core of AM ferrite rod antenna and RF coil L151 for maximum output.
- 5. Set the generator to 1400KHz and tune the receiver to the same frequency and adjust both trimming capacitors of Antenna and RF tuned circuit for maximum output.
- 6. Repeat the step 4 and 5 until no further adjustment is necessary.

Note: During tracking alignment reduce the signal generator output as necessary to avoid AGC action.

4.3 AM Signal Strength Meter Adjustment

Set the AM signal generator to 1000KHz with 74dB/M, and adjust R152 so that the signal strength meter may read 80%.

5. FM ALIGNMENT PROCEDURE

- 1. Connect a FM signal generator to the FM antenna terminals and a oscilloscope and an audio distortion analyzer to the tape output jacks on the rear panel.
- 2. Set the FM SG to 87.5MHz and provide about 3 to 5μ V. Place the tuning pointer at the low frequency end by rotating the tuning knob and adjust the core of oscillator coil L104 to obtain maximum audio output.
- 3. Set the FM SG to 108.5MHz and provide about 3 to 5μ V output. Rotate the tuning knob and place the tuning pointer at the high frequency end and adjust the trimming capacitor C106 for Maximum output.
- 4. Repeat the step 2 and 3 until no further adjustment is necessary.
- 5. Set the FM SG to 90MHz and tune the receiver to the same frequency. Decrease signal generator output until the audio output level decreases with the decreasing generator output. Adjust the antenna coil L101, RF coil L102 and L103 IF transformer L105 for minimum audio distortion.
- 6. Set the FM SG to 106MHz and tune the receiver to the same frequency. Adjust the trimming capacitor C102, C104 and C105 for minimum distortion.
- 7. Adjust the secondary core (upper) of discriminator transformer L201 so that the center tuning meter pointer indicates its center at no signal applied. Set the FM SG to 98MHz and increase its output level to $1K\mu V$ and tune the receiver to the same frequency so that the center tuning meter pointer indicates its center. Adjust the primary core (lower) of L201 for minimum distortion.
- 8. Set the FM SG to 98MHz with 100K μ V, and adjust R374 so that the signal strength meter may read 90%.

5.1 Stereo Separation Alignment

1. Set the FM SG to provide $1K\mu V$ at 98MHz. Tune the receiver to the same frequency so that the center tuning meter pointer indicates its center. Then turn off the modulation of the FM SG, connect a frequency counter to test point J310 (point ©) and adjust R311 so that the frequency counter may a precisely read 19KHz.

- 2. Modulate the FM SG with stereo composite signal consisting of only L or R channel (of course a pilot signal must be included).
- 3. Adjust the trimming resistor R301 for maximum and same separation in both channels.

5.2 Muting Circuit Alignment

- 1. Connect a VTVM across the resistor R363 and adjust the resistor R363 until the meter reads 0.75V DC at no signal.
- 2. Set the FM SG to provide $1K\mu V$ at 98MHz and tune the receiver to the same frequency correctly.
- 3. Turn on MUTING push-switch. Shift the FM signal generator frequency to plus and minus and note both plus and minus shifted frequencies at which undesirable audio side responses are muted out. Adjust the R363 so that the same shifted frequencies mute the undesirable side response.
- 4. Adjust R362 for preferred frequency shift at which the muting circuit operates.

6. TEST EQUIPMENT REQUIRED FOR SERVICING

Table 1 lists the test equipment required for servicing the Model 115B Tuner.

Item	Manufacturer and Model No.	Use
AM Signal Generator		Signal source for AM alignment.
Test Loop		Used with AM Signal generator.
FM Signal Generator	Less than 0.3% distortion.	Signal source for FM alignment.
Stereo Modulator	Less than 0.3% distortion.	Stereo separation alignment and trouble shooting.
Frequency Counter		MPX oscillator Adjustment (VCO).
Audio Oscillator	Weston Model CVO-100P, less than 0.02% residual distortion is required.	Sinewave and squarewaves signal source.
Oscilloscope	High sensitivity with DC horizontal and vertical amplifiers.	Waveform analysis and trouble shooting.
VTVM	With AC, DC, RF range.	Voltage measurements.
Circuit Tester		Trouble shooting.

Table 1. Test Equipment Required for Servicing

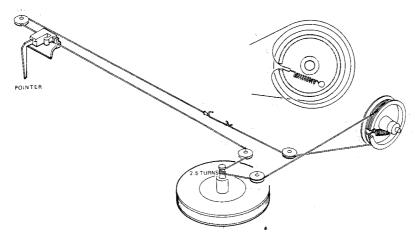


Figure 2. Dial Stringing

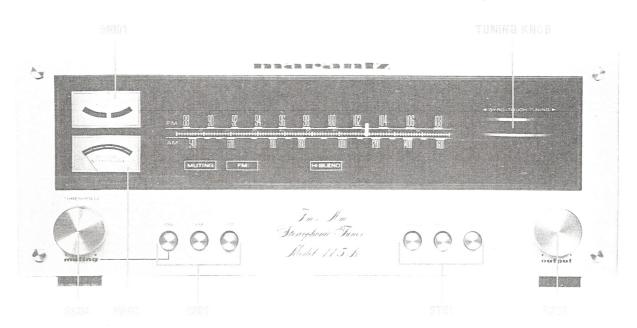


Figure 3. Front Panel Adjustment and Component Locations

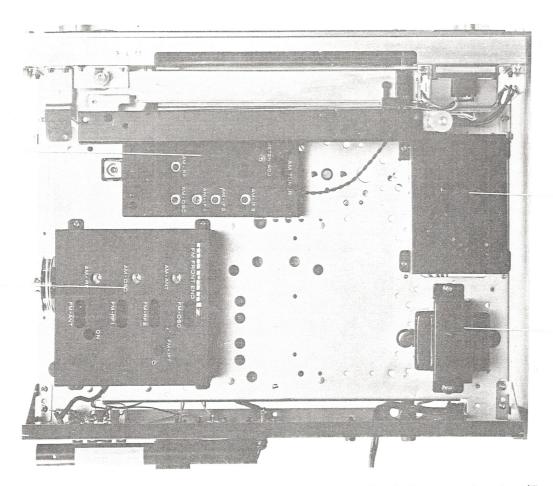


Figure 4. Main Chassis Component Locations (Top View)

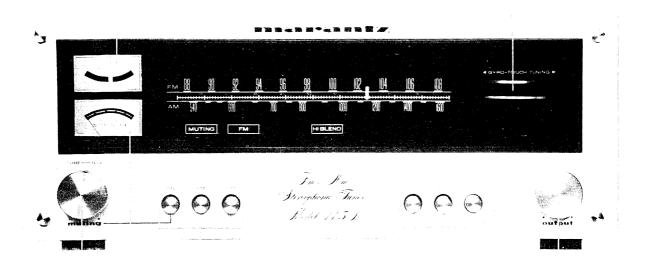


Figure 3. Front Panel Adjustment and Component Locations

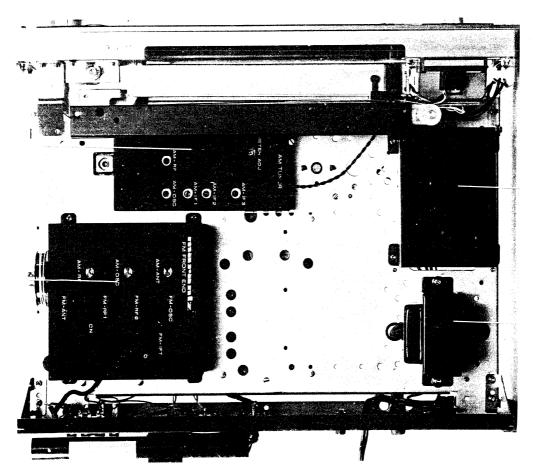


Figure 4. Main Chassis Component Locations (Top View)

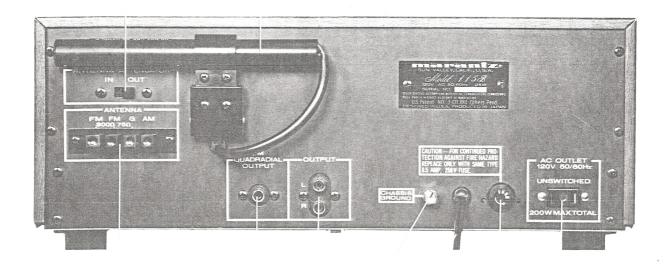


Figure 5. Rear Panel Adjustment and Component Locations

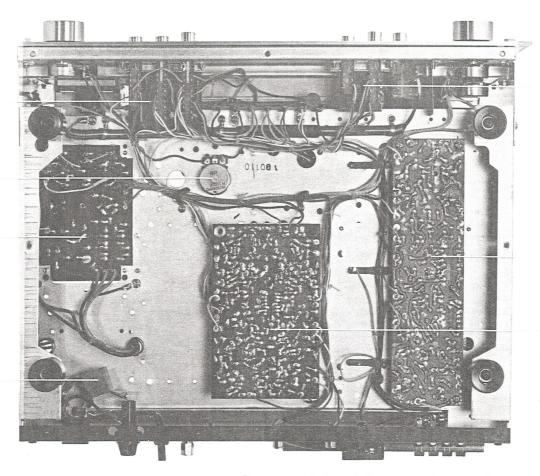


Figure 6. Main Chassis Component Locations (Bottom View)



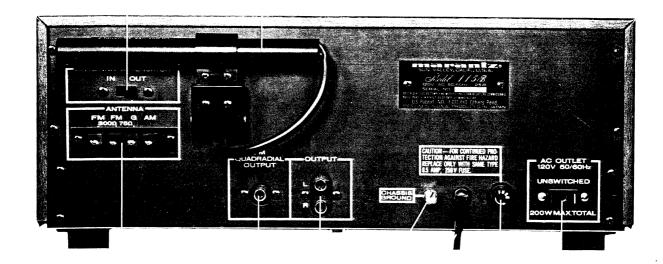


Figure 5. Rear Panel Adjustment and Component Locations

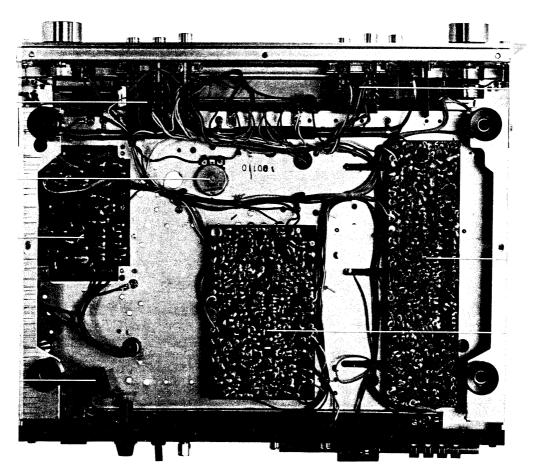


Figure 6. Main Chassis Component Locations (Bottom View)

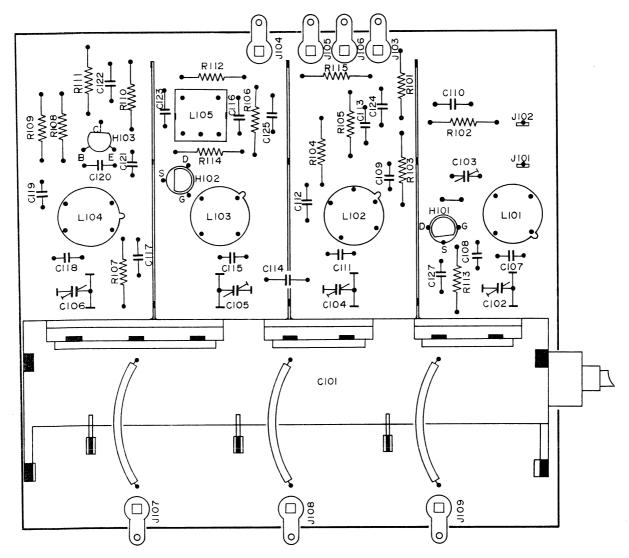


Figure 7. FM Front End Assembly P100 Component Locations

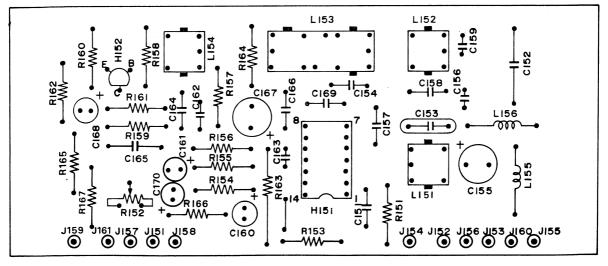


Figure 8. AM Tuner Unit Assembly P150 Component Locations

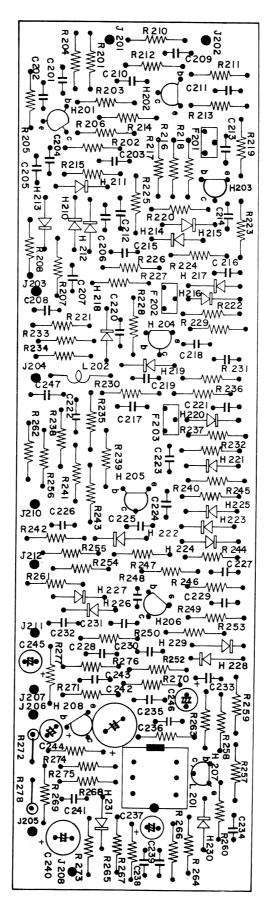


Figure 9. FM IF Amplifier Assembly P200 Component Locations

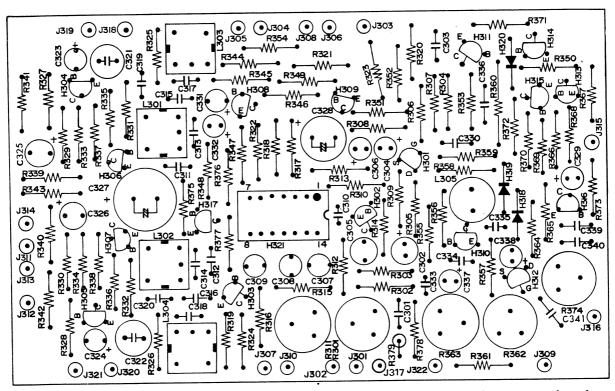


Figure 10.FM MPX Stereo Decoding and Noise DC Amplifier Assembly P300 Component Locations

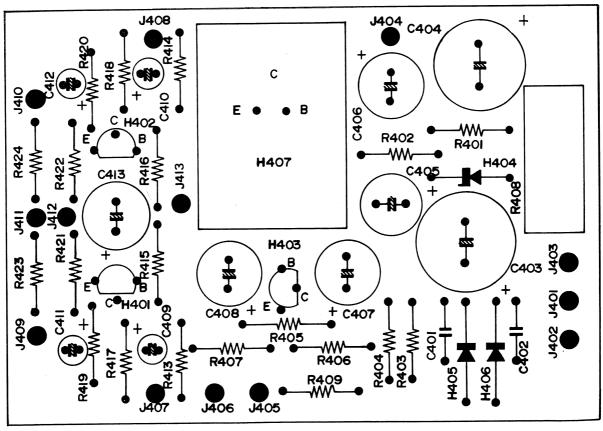


Figure 11. Power Supply Unit Assembly P400 Component Locations



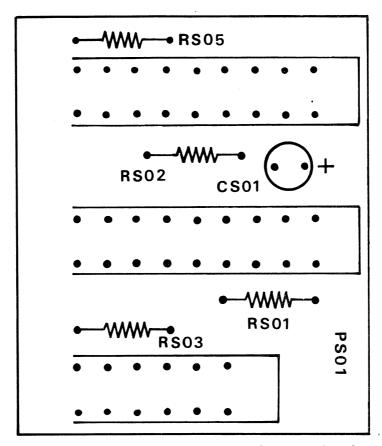


Figure 12. Selector Push Switch Assembly PS01 Component Locations

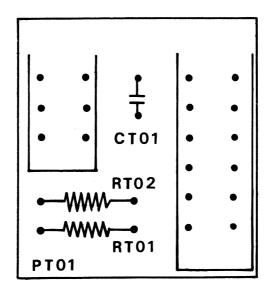


Figure 13. Mono Push Switch Assembly PT01 Component Locations

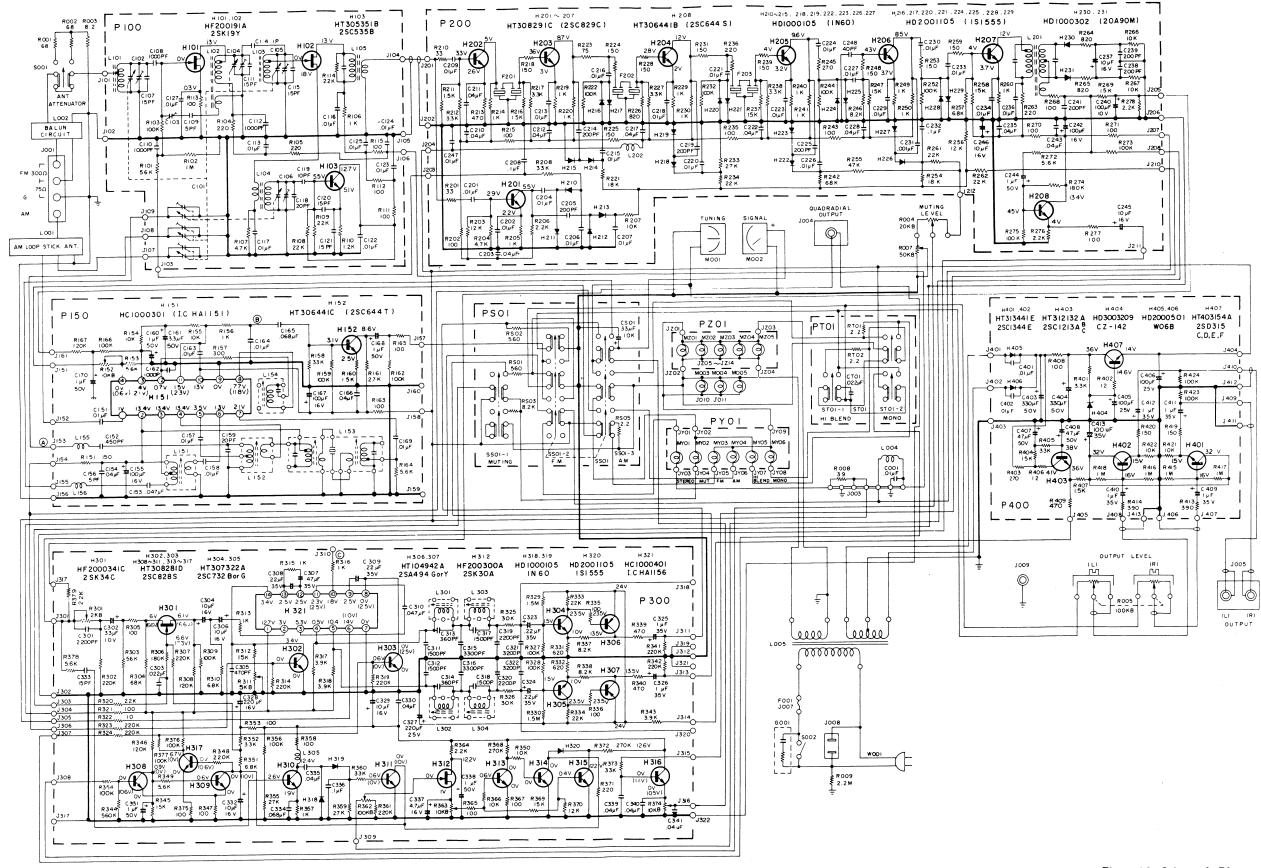


Figure 14. Schematic Diagram

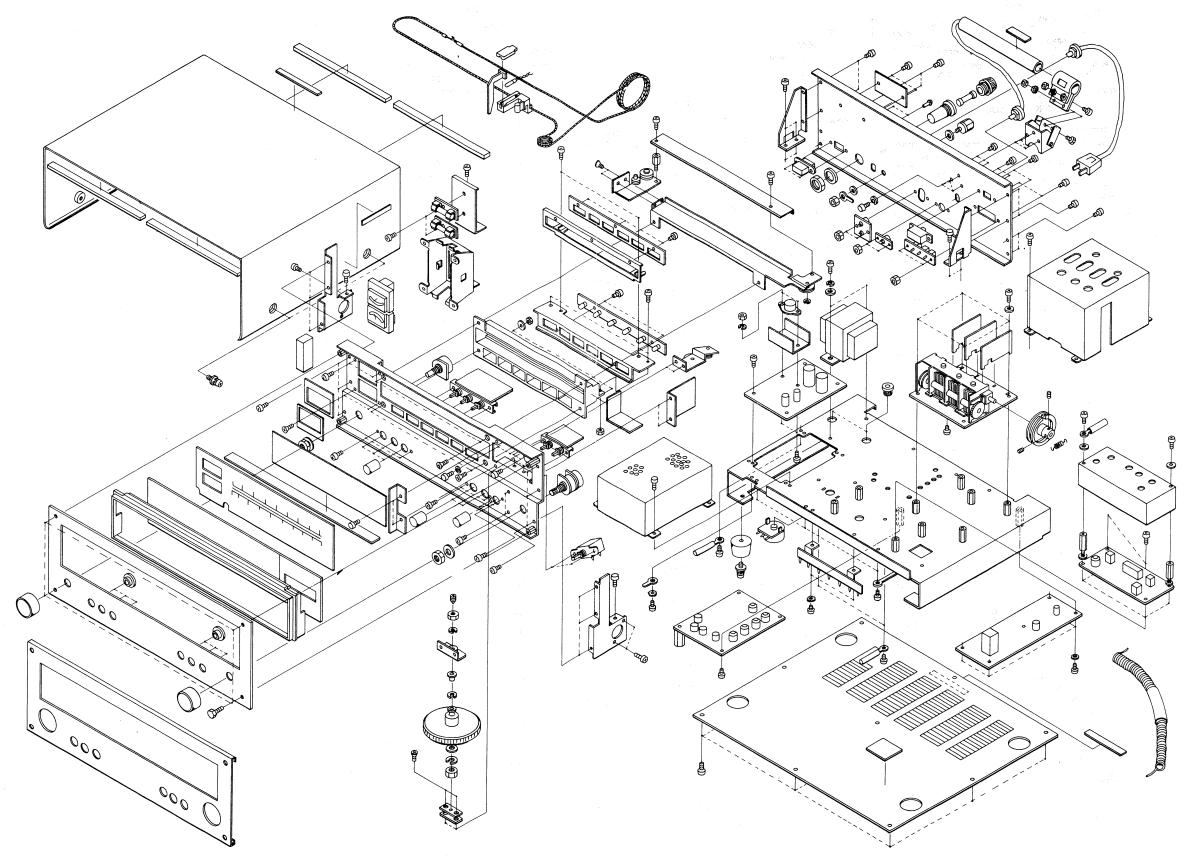


Figure 15. Exploded Mechanical Diagram

7. PARTS LIST

REF. DESIG.	MARANTZ PART NO.	DESCRIPTION
A 0103	288406340 288406301	Front Panel Assembly, For U.S.A. Escutcheon
0104	285540101	Frame
0105 0106	288415801 281825905	Window Bush x 6
0106	288405301	Cover
Α1	288406341	Front Panel Assembly, For CANADA
0103	288406301	Escutcheon
0104 0105	285540101 288415801	Frame Window
0106	281825905	Bush × 6
		Dan Assaulto
B	282610341	Pointer Assembly Pointer
0527 0528	281810301 282610301	Pointer
0528	281805301	Cover
M005	IN1008030	Lamp
0	120200640	String Assembly
C 0532	72080802A	String Assembly
0533	120225801	Hook
	005227240	The Whool Accombine
D 0604	285227340 257706302	Fly Wheel Assembly Escutcheon × 2
0604 0605	257706302	Fly Wheel
0606	285211201	Shaft
0610	53110603E	Hexagon Nut
0611	54040602N	Spring
0612	54020601E	Flat Washer P
Ε	281915940	Drum Assembly
1004	281915901	Drum
1005	71 101569M	Spring
1006	51650304D	Set Screw x 2
F	285216040	Rear Panel Assembly
0803	285216001	Bracket
0912	55060365S YJ0400018	T.R. Rivet x 2 Socket
J008	Y J0400018	Socket
	VD0040000	DW Board FM Front End
P100	YD2819002 ZZ2819002	P.W. Board, FM Front End P.W. Board Ass'y
		RESISTORS
		All resistors are ±5% and ¼W.
R101	RT0556314	56KΩ
R102	RT0510514 RT0510414	1MΩ 100KΩ
R103	RT0522114	220Ω
R105	RT0522114	220Ω
R106	RT0510214	1ΚΩ
R107	RT0547214	47ΚΩ
R108	RT0522314	22KΩ
R109 R110	RT0522314 RT0512214	22KΩ 1.2KΩ
R111	RT0510114	100Ω
R112	RT0510114	100Ω
R113	RT0510114 RT0522314	100Ω 22ΚΩ
	n 1 0022014	

REF. DESIG.	MARANZ PART NO.	D	ESCRIPTION	
		CARACITO	DC	
C102	CT1100001	CAPACITO Trimming,	n3 1.5∼10PF	
C102	CT1100001	Trimming,	1.5~10PF	
	CT1100002 CT1100001	Trimming,		
C104		σ,		
C105	CT1100001	Trimming,	1.5~10PF	
C106	CT1100001	Trimming,		
C107	DD1615001	Ceramic,	15PF ± 10%	
C108	DK1710201	Ceramic,	1000PF ± 20%	
C109	DD1105001	Ceramic,	5PF ± 0.5PF	
C110	DK1710201	Ceramic,	1000PF ± 20%	
C111	DD1615001	Ceramic,	15PF ± 10%	
C112	DK1710201	Ceramic,	1000PF ± 20%	
C113	DK1710301	Ceramic,	$0.01 \mu F \pm 20\%$	
C114	DD1001001	Ceramic,	1.0PF ± 0.25PF	
C114	DD1615001	Ceramic,	15PF ± 10%	
	DK1710301	Ceramic,	0.01µF ± 20%,	ΥY
C116	DK1710301		$0.01\mu F \pm 20\%$, $0.01\mu F \pm 20\%$,	Ϋ́Υ
C117		Ceramic,		
C118	DD1620003	Ceramic,	20PF ± 10%,	SH
C119	DD1210006	Ceramic,	10PF ± 1PF,	CH
C120	DD1615003	Ceramic,	15PF ± 10%,	CH
C121	DD1615003	Ceramic,	15PF ± 10%,	СН
0100	DK1710201	Caramia	0.01μF ± 20%,	YY
C122	DK1710301	Ceramic,	•	
C123	DK1710301	Ceramic,	$0.01\mu F \pm 20\%$	YY
C124	DK1710301	Ceramic,	$0.01\mu F \pm 20\%$	YY
C128	DK1710301	Ceramic,	$0.01 \mu F \pm 20\%$	YY
C127	DK1710301	Ceramic,	$0.01 \mu F \pm 20\%$	YY
		COUS & T	TRANSFORMER	
L101	LA1202603	Ant Coil	,	
	LA1203601	Ant Coil		
L101		1		
L102	LA1202604	RF Coil		
L103	LA1202605	RF Coil		
L104	LO1202603	OSC Coil		
L105	LI1001601	IFT		
		MISCELLA	NEOUS	
H101	HF200191A	Transistor,	2SK19Y	
H102	HF200191A	Transistor,		
H103	HT305351B	1	2SC535B	
11,00				
J101	YP1000094	Plug.		
J102	YP1000094	Plug		
J103	57271240W	Lug Eyelet		
J104	57271240W	Lug Eyelet		
J105	57271240W	Lug Eyelet		
J106	57271240W	Lug Eyelet		
J100	57271240W	Lug Eyelet		
J107	57271240W	Lug Eyelet		
J108	57271240W	Lug Eyelet		
1016	273010903	Shield	x 3	
1011	281905102	Guide		
1012	51060305E	P.H.M. Scre	ew x 3	
C101	CA4330001	Variable Ca	p.	
P150	YD2890001	P.W. Board	, AM Tuner	
	ZZ2884101	P.W. Board	•	
		1		

	EF.	M. P.	ARA ART	NZ N 0.			DES	SCRIPTION	
F F F F F F F F F F F F F F F F F F F	R151 R152 R153 R154 R155 R156 R157 R158 R159 R160	RRRRRR	TO 51 AO 10 TO 55 TO 51 RTO 51 RTO 53 RTO 53 RTO 51 RTO 51	5114 03025 66214 0314 0314 10214 30114 33314			rs aı	re ± 5% and ¼W, ise indicated.	
	R161 R162 R163 R164 R165 R166 R167 R168	F	RTO51 RTO51	10414		2.7KΩ 100KΩ 100Ω 5.6KΩ 100Ω 100KΩ 120KΩ 1.5KΩ			
	C151 C152 C153 C154 C155 C157 C158 C159 C160 C161		DF 65 DF 17 DK 18 EA 10 DK 17 DK 17 DD 16	10301 45101 47305 40302 70169 710301 710301 520001 550509 850509		CAPACIT Ceramic, Film, Film, Ceramic, Electroly Electroly Electroly Electroly Electroly		$\begin{array}{l} \text{RS} \\ 0.01 \mu \text{F} \pm 20\% \\ 450 \text{PF} \pm 5\% \\ 0.047 \mu \text{F} \pm 20\% \\ 0.04 \mu \text{F} + 80\% , -20\% \\ 100 \mu \text{F} , 16V \\ 0.01 \mu \text{F} \pm 20\% \\ 0.01 \mu \text{F} \pm 20\% \\ 20 \text{PF} \pm 10\% \\ 1 \mu \text{F} , 50V \\ 3.3 \mu \text{F} , 50V \end{array}$	6
	C162 C163 C164 C165 C166 C167 C168 C169 C170		DK 17 DF 17 DF 16 DK 18 EA 10 EA 10	710201 710301 710301 668305 340302 070169 050509 710301 050509		Ceramic, Film, Ceramic, Film, Ceramic, Electroly Ceramic, Electroly	(, (,	$\begin{array}{l} 1000 \text{PF} \pm 20\% \\ 0.01 \mu \text{F} \pm 20\% \\ 0.01 \mu \text{F} \pm 20\% \\ 0.068 \mu \text{F} \pm 10\% \\ 0.04 \mu \text{F} + 80\%, -20\% \\ 100 \mu \text{F}, & 16V \\ 1 \mu \text{F}, 50V \\ 0.01 \mu \text{F} \pm 20\% \\ 1 \mu \text{F}, & 50V \\ \end{array}$	%
	H151 H152		HC10	000301 06441C		SEMICO IC, Transisto		UCTORS IC HA1151 2SC644T	
	L151 L152 L153 L154 L155 L156		LA10 LO10 LI10 LI10	001 017 001 048 028002 001 064 332002 332002		RF Coil, OSC Coi IFT, IFT, Choke C	l, oil, oil,		
	J151 { J158		YP1	000113		Plug	. _ Al		
	J161		YP1	000113		Plug			
	P200)	YD: ZZ2	2884006 2884006	;	P.W. Boo			
	1		l		⊥				

REF. DESIG.	MARANZ PART NO.	DESCRIPTION
		RESISTORS
5004	DT0522014	All resistors are \pm 5% and $\%$ W. 33Ω
R201 R202	RT0533014 RT0510114	100Ω
R203	RT0512314	12Ω
R204	RT0547214	12ΚΩ
R205 R206	RT0510214 RT0522214	1ΚΩ 2.2ΚΩ
R207	RT0522214	10ΚΩ
R208	RT0533314	33ΚΩ
R210	RT0533014	150Ω
R211	RT0515214	1.5ΚΩ
R212	RT0533214	3.3ΚΩ
R213	RT0547114	470Ω
R214	RT0510214	1ΚΩ 100Ω
R215 R216	RT0510114 RT0515214	1.5KΩ .
R217	RT0533214	3.3ΚΩ
R218	RT0515114	150Ω
R219	RT0510214	1ΚΩ 1ΚΩ
R220 R221	RT0510214 RT0518314	18ΚΩ
11221	1110010011	10112
R222	RT0510414	100ΚΩ
R223	RT0575014 RT0515114	75Ω 150Ω
R225	RT0515114	150Ω
R226	RT0582114	820Ω
R227	RT0533214	3.3ΚΩ
R228 R229	RT0515114 RT0510214	150Ω 1KΩ
R230	RT0510214	1ΚΩ
R231	RT0515114	150Ω
R232	RT0510414	100ΚΩ
R233	RT0527314	27ΚΩ
R234	RT0522314	22ΚΩ
R235 R236	RT0510114 RT0522114	100Ω 220Ω
R237	RT0515214	1.5ΚΩ
R238	RT0533214	3.3ΚΩ
R239	RT0515114 RT0510214	150Ω 1KΩ
R240 R241	RT0510214	1ΚΩ
R242 R243	RT0568314	68ΚΩ 100Ω
R243	RT0510114 RT0510414	100Ω
R245	RT0527114	270Ω
R246	RT0582214	8.2ΚΩ
R247 R248	RT0515314 RT0515114	15ΚΩ 150Ω
R249	RT0510214	1ΚΩ
R250	RT0510214	1ΚΩ
R252	RT0510414	100ΚΩ
R253	RT0515114	150Ω
R254	RT0518314	18ΚΩ
R255	RT0547314	47KΩ
R256 R257	RT0512314 RT0568214	12ΚΩ 6.8ΚΩ
R258	RT0515314	15ΚΩ
R259	RT0515114	150Ω
R260 R261	RT0510214 RT0522314	1KΩ 22KΩ
R261	RT0522314	22ΚΩ
L		

REF. DESIG.	MARANZ PART NO.	DESC	CRIPTION	REF. DESIG.	MARANZ PART NO.	D	ESCRIPTION
R263	RT0522114	220Ω		C247	DK1710301	Ceramic,	0.01μF ± 20%
R264	RT0522114	820Ω	1	C248	DD1540001	Ceramic,	40PF ± 5%
R265	RT0582114	820Ω					
R266	RT0510314	10ΚΩ	1			FILTERS	
R267	RT0510314	10ΚΩ	1	F201	FF1107004	Ceramic Filt	· 1
R268	RT0510114	100Ω		F202	FF1107004	Ceramic File	· ·
R269	RT0515314	15ΚΩ	1	F203	FF1107004	Ceramic Filt	ter, CFS107M
R270	RT0510114	100Ω				SEMICOND	UCTORS
R271	RT0510114	100Ω		H201	HT308291C	Transistor,	2SC829 C
R272	RT0556214	5.6ΚΩ	1	H202	HT308291C	Transistor.	2SC829 C
R273	RT0510414	100ΚΩ		H203	HT308291C	Transistor,	2SC829 C
R274	RT0518414	180ΚΩ		H204	HT308291C	Transistor,	2SC829 C
R275	RT0510414	100ΚΩ		H205	HT308291C	Transistor,	2SC829 C
R276	RT0522214	2.2ΚΩ		H206	HT308291C	Transistor,	2SC829 C
R277	RT0510114	100Ω		H207	HT308291C	Transistor,	2SC829 C
R278	RT0522214	2.2ΚΩ		H208	HT306441B	Transistor,	2SC644 S
				H210	HD1000105	Diode,	1N60
		CAPACITORS		H211	HD1000105	Diode,	1N60
C201	DK1710301	,	.01μF ± 20%	H212	HD1000105	Diode,	1N60
C202	DK1710301		.01μF ± 20%	H213	HD1000105	Diode,	1N60
C203	DK1840302		.04μF +80%, -20% .01μF ± 20%	H214	HD1000105	Diode,	1N60
C204 C205	DK1710301 DD1620101	1	00PF ± 10%	H215	HD1000105	Diode,	1N60
C205	DK1710301		.01µF ± 20%	H216	HD2001105	Diode,	1S1555
C200	DK1710301	1	.01µF ± 20%	H217	HD2001105	Diode,	1S1555
C208	DK1810402		.1µF +80%, -20%	H218	HD1000105	Diode,	1N60
C209	DK1710301		.01μF ± 20%	H219	HD1000105	Diode,	1N60
C210	DK1840302	Ceramic, 0	.04μF +80%, -20%	H220	HD2001105	Diode,	1S1555
		_		H221	HD2001105	Diode,	1S1555
C211	DK1840302		.04μF +80%, -20%		1104000405	Dia I	11100
C212	DK1840302		.04μF +80%, -20%	H222	HD1000105	Diode, Diode,	1N60 1N60
C213	DK1710301		.01μF ± 20% 00PF ± 10%	H223 H224	HD1000105 HD2001105	Diode,	1S1555
C214	DD1620101	,	.01μF ± 20%	H225	HD2001105	Diode,	1S1555
C215	DK1710301 DK1710301		.01 µF ± 20%	H226	HD1000105	Diode,	1N60
C216 C217	DK1710301		.04µF +80%, -0%	H227	HD1000105	Diode,	1N60
C217	DK1710301		.01µF ± 20%	H228	HD2001105	Diode,	1S1555
C219	DD1620101	Ceramic, 2	00PF ± 10%	H229	HD2001105	Diode,	1S1555
C220	DK1710301	Ceramic, 0	.01μF ± 20%	H230	HD1000302	Diode,	20A90M
				H231	HD1000302	Diode,	20A90M
C221	DK1710301	· · · · · · · · · · · · · · · · · ·	.01μF ± 20%	1			NEOUS
C222	DK1840302		0.04μF +80%, -20%	1 201	1 11401633	MISCELLA	FM
C223	DK1710301		0.01μF ± 20% 0.01μF ± 20%	L201 L202	LI1401623 LC1332002	IFT, Choke Coil,	
C224	DK1710301	,	00PF ± 10%	L202	LC1332002	Choke Con,	, 3.3μ11
C225 C226	DD1620101 DK1710301		0.01μF ± 20%	J201			
C227	DK1710301		0.01μF ± 20%	1	YP1000113	Plug	
C228	DK1840301		.04μF +80%, -20%	J208			
C229	DK1710301	Ceramic, 0	0.01μF ± 20%				
C230	DK1710301	Ceramic, 0	0.01μF ± 20%	J210			
				\ \?	YP1000113	Plug	
C231	DK1710201		0.001µF ± 20%	J212			
C232	DK1810402		0.1μF +80%, -20% 0.01μF ± 20%				
C233	DK1710301	1 .	0.01µF ± 20%	P300	YD2890003	P.W. Board	FM MPX & Noise DC Amp.
C234	DK1710301	,	0.04µF +80%, -20%	F 300	ZZ2884103	P.W. Board,	
C235	DK1840302	,	0.01 µF ± 20%		22207100		, ,
C236	DK1710301 EA1060169	•	0μF, 16V	1		RESISTOR	s
C237	DD1620101	,	200PF ± 20%			1	are ± 5% and ¼W,
C239	DD1620101		200PF ± 20%			1	wise indicated.
C240	EA1070109		00μF, 10V	R301	RA0202011	Trimming,	2KΩ (B)
		''		R302	RT0522414	220ΚΩ	
C241	DD1620101		00PF ± 20%	R303	RT0556314	56KΩ	
C242	EA1070169	1	00μF, 16V	R304	RT0568314	68KΩ	
C243	DK1840302		0.04μF +80%, -20%	R305	RT0510114	100Ω	
C244	EA1050509		μF, 50V	R306	RT0518414	180KΩ	
C245	EA1060169		0μF, 16V	R307 R308	RT0522414 RT0512414	220KΩ 120KΩ	
C246	EA1060169	Electroly, 1	0μF, 16V	11306	1110012414	120132	

R300 RTOS 10414 RTOS 68274 FOR 10414 R372 RTOS 22144 R373 RTOS 22144 R373 RTOS 10414 R374 RTOS 22144 R376 R376 RTOS 10516 R374 RTOS 23144 R376 RTOS 10516 R375 RTOS 10514 R378 RTOS 10514 RTOS 1051	REF.		DESCRIPTION	RE DES		MARANTZ PART NO.	DE	SCRIPTION	
R310 RT068214 ABX BBXΩ (B)			10000	B2	71	BT0522114	220 O		
R311				1 1					
RAJE	R310	RT 0568214	0.0K12		1				
RTOS		D 0 0 E 0 20 20	Trimming 5KO (B)	1 1				10KΩ (B)	
R312			J	1 1	- 1	i i			
R316					- 1	1			
R378 R70580214 KED R379 R70580214 R379				1 1		· ·			
High HT0510214 HXD HXD	1		1	1 1	1				
R318			1	1 1	- 1	RT0522214	2.2KΩ		
R319 R105.29214 230KΩ C30					-				
R320 RT0522414 220KΩ C301 DF1622205 Film, D30F ± 10V Fi							CAPACITO	RS	
R320				сз	01	DF1622205	Film,	2200PF ± 10%	
R321 RT051 0114 100Ω C303 DF1722305 Film, D0224 Film R322 RT051 0114 R322 RT051 0114 R324 RT0522414 R326 RT0522414 R326 RT0530314 R326 RT0530314 R326 RT0530314 R326 RT0530314 R326 RT0530314 R326 RT0530314 R326 RT0543114 R328 RT051 0414 R328 RT052 0414 R328 RT051 0414 R328 RT052 0414 R32			l .			EA3360109	Electroly,	33μF, 10V	
100 100	H32	h 1002201.		c3	803	DF1722305	Film,	$0.022 \mu F \pm 20\%$	
R322 RTOS 10014 100 1	B22	BT0510114	100Ω	c3	04	EA1060169	Electroly,		
R323			1	c3	105	DF5547101	Film,	470PF ± 5%	
R324 RT0522414 220KΩ C396 E027490501 Electroly, 0.22µ ± 20K, 35V R326 RT0530314 R326 RT0530314 R326 RT0510414 R328 RT0510414 R328 RT0510414 R329 RT0515514 R330 RT0515514 R330 RT0515514 R330 RT051514 R330 RT051514 R330 RT0522314 R336 RT0522314 R336 RT0510114 R337 RT0522314 R336 RT0510114 R337 RT0582214 R339 RT0547114 R339 RT0547114 R339 RT0547114 R330 RT0547114 R334 RT0552414 R335 RT0510114 R335 RT0510114 R336 RT05			1	C3	306	EA1060169	Electroly,		
R325			I .	C3	307	EQ4740501	Electroly,	•	
R326			30ΚΩ	C3	808	EQ2240501	Electroly,		
RTOS1 0414 100KΩ			30ΚΩ	C3	309	EQ2240501	Electroly,	•	
R708 R708 1044 R330 R708 15814 1.8MΩ C312 DF1515205 C313 DF1515205 C313 DF1515205 C314 DF1515205 DF1515205 C314 DF1515205			100ΚΩ	C3	310	DF1747301	Film,	$0.047 \mu F \pm 20\%$,	35V
R329 R70515514 1.5MΩ C312 C313 DF1515205 Film, 1500PF ±5% Film, 1500PF ±			100ΚΩ						
R330 RT0515514 1.5MΩ C312 DF1515205 C313 D1536101 C313 D1536101 C314 D1536101 C315 D1536101 C315 D1536101 C315 C31	1		1.5ΜΩ	C3	311	DF1515205			
R331 R70562114 620Ω C314 C314 D1536101 C274 C315 D1536101 C314 D1536101 C314 D1536101 C314 D1536101 C314 D1536101 C314 D1536101 C314 D1536101 C315 D1533205 Film, 3300PF ±5% Film, 200PF ±5% Film,			1.5ΜΩ	C3	312	DF1515205	Film,		
H331 RT0562114 R300 C315 DF1833205 DF1833205 Film, 3300FF ± 5% Film, 1500FF ± 5% Film,	'''			C3	313		,		
R332 RT0562114 22KΩ C316 DF153205 DF153205 Film, 3300F± 5% Film, 1500F± 5% Film, 2200F± 5% Film,	B33	1 RT0562114	620Ω	C3	314				
R333			620Ω			ŧ			
R334 RT0522314 100Ω C318 DF151205 Film, 1500FF ± 5% Film, 2200FF ± 5%			22ΚΩ			1	1		
R335 RT0510114 100Ω C318 DF1518205 Film, 2000F ± 5% R348 RT0510114 100Ω C320 DF1522205 Film, 2000F ± 5% Film, 2000F ± 3% Film, 2000F ± 20% Film,			22ΚΩ	1 1		1			
R336			100Ω	1 1					
R337			100Ω				1 .		
R338 RT05822114 470Ω C321 DF5532201 Film, 3200PF ± 3% 320PF ± 20% 35V			8.2ΚΩ	C3	320	DF1522205	Film,	2200PF ± 5%	
R339 R10547114 470Ω C322 DF5532201 Film 3200PF±3% Electroly, 0.22μF±20%, 35V C324 R70522414 220KΩ C325 EV1050352 Electroly, 0.22μF±20%, 35V C325 EV1050352 Electroly, 0.22μF±20%, 35V C325 EV1050352 Electroly, 0.22μF±20%, 35V C326 EV1050352 Electroly, 0.22μF±20%, 35V C327 EA2270599 Electroly, 0.22μF±20%, 35V C327 EA2270599 Electroly, 0.22μF±20%, 35V C326 EV1050352 Electroly, 0.22μF±20%, 35V C326 EV1050352 Electroly, 0.22μF±20%, 35V C327 EA2270599 Electroly, 0.22μF±20%, 35V C326 EA2270169 Electroly, 0.22μF±20%, 35V Electroly, 0.22μF±20%, 35V Electroly, 0.22μF±20%, 35V C326 EA2270169 Electroly, 0.22μF±20%, 35V Electroly, 0.22μF±20%, 35V Electroly, 0.22μF±20%, 35V Electroly, 0.22μF±20%, 35V Electroly, 0.22μF±20%, 232 EA1060169 Electroly,			1			DEEE00004	F11	22000 + 20/	
R340 RT0547114 470Ω C322 DF-53220T Electroly, 0.22μ ± 20%, 35V Electroly, 1μF ± 20%, 35V Electroly, 10μF ± 20%, 35V Electroly, 10μF, 16V E			470Ω	1 1			1		
R341 RT0522414 220KΩ C324 EV2240351 Electroly, 0.22μF±20%, 35V Electroly, 1μF±20%, 35V Electroly, 10μF, 16V Elec			470Ω	1 1					251/
R341 RT0522414 220KΩ C325 EV1050352 Electroly, 1μ F ± 20%, $35V$ R343 RT0522414 3,9KΩ C326 EV1050352 Electroly, 1μ F ± 20%, $35V$ R344 RT0515314 ISKΩ C326 EV1050352 Electroly, 1μ F ± 20%, $35V$ R345 RT0515314 ISKΩ C328 EA2270259 Electroly, 220μ F, $25V$ R346 RT0510114 100Ω C329 EA1060169 Electroly, 20μ F, $16V$ R348 RT0510114 100Ω C330 DK1840302 Ceramic, 0.04μ F ±80%, -20% R350 RT0510314 10KΩ C331 EA1050509 Electroly, 10μ F, $16V$ R351 RT056214 6.8KΩ C331 C335 DF1740301 Film, 0.068μ F ±10% R352 RT0510414 100Ω C336 C337 EA4750359 Electroly, 10μ F, $16V$ R353 RT0510414 100Ω C336 EA4750359 Electroly, 10μ F, $16V$ R356 RT0510214 IKΩ C336 EA4750359 Electroly, 10μ F, $16V$ <td></td> <td></td> <td></td> <td></td> <td></td> <td>l .</td> <td></td> <td>•</td> <td></td>						l .		•	
R342 R70529214 20KΩ R346 R70569214 560KΩ C327 E2707059 Electroly, 220μF, 25V Electroly, 220μF, 16V Electroly, 220μF, 220μ	R34							•	
R343 R105-9214 3.9 kV R344 R105-66414 560 kΩ C327 EA2270259 Electroly, 220 μF, 25 V R346 R10512414 120 kΩ C328 EA2270169 Electroly, 220 μF, 16 V R346 R10510114 100 Ω C330 DK1840302 Ceramic, 0.04 μF +80%, -20% R348 R105522414 220 kΩ C331 EA1060169 Electroly, 10 μF, 16 V R350 R10510314 10 kΩ C332 D1615001 Ceramic, 15FF ± 10% R351 R10568214 6.8 kΩ C333 D1615001 Ceramic, 15FF ± 10% R353 R10510114 100 Ω C336 DK1810402 Ceramic, 15FF ± 10% R353 R1051014 100 Ω C336 DK1810402 Ceramic, 0.04 μF ± 20% R354 R1051014 100 Ω C336 DK1840302 Ceramic, 0.1 μF +80%, -20% R356 R10510314 100 κΩ C339 DK1840302 Ceramic, 0.04 μF +80%, -20% R358 R10510114 100 κΩ C34 DK1840302 <t< td=""><td>R34</td><td></td><td>1</td><td></td><td></td><td>1</td><td></td><td></td><td></td></t<>	R34		1			1			
R344 R10515314 SKΩ C328 EA2270169 Electroly, 220μF, 16V R346 R10515314 120KΩ C330 DK1840302 Ceramic, 0.04μF +80%, -20% R349 R10556214 5.6KΩ C331 EA1060169 Electroly, 10μF, 16V Ceramic, 0.04μF +80%, -20% R350 R10510314 10KΩ C332 EA1060169 Electroly, 10μF, 16V Ceramic, 0.04μF +80%, -20% R351 R10568214 6.8KΩ C332 EA1060169 Electroly, 10μF, 16V C332 EA1060169 Electroly, 10μF, 16V C333 DD1615001 C233 EA1060169 Electroly, 10μF, 16V C334 DD1615001 C233 DD1615001 C233 DD1615001 C233 DD1615001 C233 DD1615001 C233 DD1615001 C233 EA1050509 Electroly, 10μF + 80%, -20% C335 EA1050509 Electroly, 10μF + 80%, -20% C336 EA1050509 Electroly, 10μF + 80%, -20% C338 EA1050509 Electroly, 10μF + 80%, -20% C339 DK1840302 C239	R34		1			1	1		00 1
R345 R1051512414 120 KΩ C329 E41060169 C330 DK1840302 Ceramic, 10μF, 16V C0μF, 16V C0μF	R34					I .	1		
R346	R34		1	1 1		1			
R347 R1051044 100 Ω R348 RT0522414 220K Ω R349 RT0556214 5.6K Ω R350 RT0510314 10K Ω C332 EA1060169 Electroly, 10 μ F, 16V R351 RT0568214 6.8K Ω C334 D71615001 Film, 0.06 μ F ± 10% R352 RT0533314 33K Ω C335 DF1740301 Film, 0.04 μ F ± 20% R353 RT0510114 100 Ω C336 DK1810402 Ceramic, 0.1 μ F + 80%, -20% R354 RT0510414 100K Ω C337 EA4750359 Electroly, 4.7 μ F, 35V R355 RT0527314 27K Ω C338 EA1050609 Electroly, 4.7 μ F, 50V R356 RT0510414 100K Ω C339 DK1840302 Ceramic, 0.04 μ F +80%, -20% R357 RT0510214 1K Ω C340 DK1840302 Ceramic, 0.04 μ F +80%, -20% R368 RT0510314 100 Ω C341 DK1840302 Ceramic, 0.04 μ F +80%, -20% R361 RT0522414 220K Ω Trimming, 100K Ω	R34		l .						%
R349 R350 RT0556214 RT0510314 5.6KΩ 10KΩ C331 C332 EA1050509 EA1060169 Electroly, 10μF, 16V Electroly, 10μF, 16V Ceramic, 15PF ± 10% R351 R352 R353 R353 R354 R355 R354 R355 R70510414 R355 R356 R356 R357 R70510214 R357 R357 R357 R357 R358 R358 R359 R359 R360 6.8KΩ A3KΩ A3KΩ A3KΩ A3KΩ A3KΩ A3KΩ A3KΩ A3			1	110	330	DK 1040302	Octainic,	0.0101 .00%, 20	
R349 R 10596214 5.682 $10KΩ$ $C332$ EA1060169 Electroly, $Coramic, 15PF \pm 10\%$ R351 R 70568214 $6.8KΩ$ $C334$ DF1668301 Film, $C336$ $0.068μF \pm 10\%$ R352 R 70510114 $100Ω$ $C336$ DK1810402 Ceramic, $C36$ $C164$ R353 R 70510414 $100ΩΩ$ $C336$ DK1810402 Ceramic, $C36$ $C14F + 80\%, -20\%$ R355 R 70510414 $100KΩ$ $C336$ EA4750359 Electroly, $A.7μF, 35V$ R356 R 70510414 $100KΩ$ $C339$ DK1840302 Ceramic, $C.0.04μF + 80\%, -20\%$ R357 R 70510214 $100ΩΩ$ $C340$ DK1840302 Ceramic, $C.0.04μF + 80\%, -20\%$ R358 R 70510114 $100ΩΩ$ $C340$ DK1840302 Ceramic, $C.0.04μF + 80\%, -20\%$ R361 R 70522414 $27ΚΩ$ $C340$ DK1840302 Ceramic, $C.0.04μF + 80\%, -20\%$ R362 R A0104018 $C340$ $C340$ $C340$ $C340$ $C340$ $C340$ $C340$ C			1	~	221	EA1050509	Flectroly	1uF 50V	
R350 R10510314 10KΩ C333 DD1615001 Ceramic, 15PF ± 10% R351 R70568214 6.8KΩ C334 DF1668301 Film, 0.068μF ± 10% R352 R705101011 100Ω C336 DK1810402 Ceramic, 0.1μF +80%, -20% R354 R70510414 100KΩ C337 EA4750359 Electroly, 4.7μF, 35V R356 R70510414 100KΩ C339 DK1840302 Ceramic, 0.04μF +80%, -20% R357 R70510214 1KΩ C340 DK1840302 Ceramic, 0.04μF +80%, -20% R358 R70510114 100Ω C341 DK1840302 Ceramic, 0.04μF +80%, -20% R361 R70527314 27ΚΩ C341 DK1840302 Ceramic, 0.04μF +80%, -20% R362 RA0104018 Trimming, 10KΩ H301 H520342C FET, 2SK34C, D R363 RA01030325 Trimming, 10KΩ (B) H302 H308281D Transistor, 2SC828S R364 R70512114 100Ω H304 H307322A Transistor, 2SC732 B or G R366 R						1			
R351 RT0568214 6.8 KΩ C334 DF1668301 Film, 0.068μF ± 10% R352 RT0533314 33 KΩ C335 DF1740301 Film, 0.04μF ± 20% R353 RT0510114 100Ω C336 DK1810402 Ceramic, 0.1μF ± 80%, -20% R354 RT0510414 100KΩ C337 EA4750359 Electroly, 4.7μF, 35V R356 RT0510414 100KΩ C338 EA1050509 Electroly, 1μF, 50V R357 RT0510214 1KΩ C339 DK1840302 Ceramic, 0.04μF +80%, -20% R358 RT0510114 100Ω C340 DK1840302 Ceramic, 0.04μF +80%, -20% R359 RT0522314 27KΩ C341 DK1840302 Ceramic, 0.04μF +80%, -20% R360 RT0533314 33KΩ C341 DK1840302 Ceramic, 0.04μF +80%, -20% R361 RA0104018 Trimming, 100KΩ (B) H301 HF200342C FET, 2SK34C, D Transistor, 2SC828S R363 RA0103025 Trimming, 10KΩ (B) H302 H308281D Transistor, 2SC828S <t< td=""><td> R3</td><td>50 RT0510314</td><td>10K32</td><td></td><td></td><td></td><td></td><td></td><td></td></t<>	R3	50 RT0510314	10K32						
R351 R7053314 $33KΩ$ $33KΩ$ $C335$ R70510114 $C336$ R70510414 $C336$ R7051044 $C336$ R705104 $C336$ R7051			6.8%0						
R353 RT0510114 100Ω C336 DK1810402 Ceramic, 0.1μF +80%, -20% R354 RT0510414 100ΚΩ C337 EA4750359 Electroly, 4.7μF, 35V R355 RT0510414 100ΚΩ C339 DK1840302 Ceramic, 0.04μF +80%, -20% R356 RT0510214 1ΚΩ C340 DK1840302 Ceramic, 0.04μF +80%, -20% R358 RT0510114 100Ω C340 DK1840302 Ceramic, 0.04μF +80%, -20% R359 RT0527314 27ΚΩ C341 DK1840302 Ceramic, 0.04μF +80%, -20% R360 RT0533314 33ΚΩ C341 DK1840302 Ceramic, 0.04μF +80%, -20% R361 RT0522414 220ΚΩ C341 DK1840302 Ceramic, 0.04μF +80%, -20% R362 RA0104018 Trimming, 100ΚΩ (B) H301 HF200342C FET, 25K34C, D R363 RA0103025 Trimming, 10KΩ (B) H302 HT308281D Transistor, 25C828S R364 RT0510114 100Ω H305 H304 H307322A Transistor, 25C732 B or G				1 1				•	
R354 R70510414 $100KΩ$ $27KΩ$ $27CΩ$				1 1				•	ó
R355 RT0527314 $27KΩ$ C338 EA1050509 Electroly, $1μF$, $50V$ R356 RT0510414 $100KΩ$ C339 DK1840302 Ceramic, $0.04μF + 80\%, -20\%$ R357 RT0510214 $1KΩ$ C340 DK1840302 Ceramic, $0.04μF + 80\%, -20\%$ R358 RT0510114 $100Ω$ C341 DK1840302 Ceramic, $0.04μF + 80\%, -20\%$ R361 RT0523314 $33KΩ$ C341 DK1840302 Ceramic, $0.04μF + 80\%, -20\%$ R361 RT0522414 $220KΩ$ C341 DK1840302 Ceramic, $0.04μF + 80\%, -20\%$ R361 RT0522414 $220KΩ$ C341 DK1840302 Ceramic, $0.04μF + 80\%, -20\%$ R362 RA0104018 Trimming, $100KΩ$ (B) H302 HT308281D Transistor, $25C8288$ R363 RA0103025 Trimming, $10KΩ$ (B) H303 HT308281D Transistor, $25C732$ B or G R364 RT0510114 $100Ω$ H306 HT307322A Transistor, $25C732$ B or G R366 RT0510314 $10KΩ$ H306 HT104942A Transi							1		
R356 RT0510414 100KΩ C339 DK1840302 Ceramic, O.04μF +80%, -20% R357 RT0510214 1KΩ C340 DK1840302 Ceramic, O.04μF +80%, -20% R358 RT0510114 100Ω C341 DK1840302 Ceramic, O.04μF +80%, -20% R359 RT0527314 27ΚΩ C341 DK1840302 Ceramic, O.04μF +80%, -20% R361 RT0533314 33ΚΩ SEMICONDUCTORS R362 RA0104018 Trimming, 100KΩ (B) H302 HT308281D Transistor, 2SC828S R363 RA0103025 Trimming, 10KΩ (B) H303 HT308281D Transistor, 2SC732 B or G R364 RT0522214 2.2KΩ H304 HT307322A Transistor, 2SC732 B or G R365 RT0510114 100Ω H306 HT307322A Transistor, 2SC732 B or G R367 RT0510314 10KΩ H306 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 270KΩ H308 HT308281D Transistor, 2SC828S R369 RT0515314 15KΩ H309 HT308281D Transistor, 2SC828S	•			1 1		1			
R356 R10510214 $1KΩ$ R357 R70510214 $1KΩ$ R358 R70510114 $100Ω$ R359 R70527314 $27KΩ$ R360 R70533314 $33KΩ$ R361 R70522414 $220KΩ$ H301 HF200342C FET, 2SK34C, D R362 RA0104018 Trimming, 10KΩ (B) H302 H7308281D Transistor, 2SC828S R363 RA0103025 Trimming, 10KΩ (B) H303 H7308281D Transistor, 2SC828S R364 R70522214 $2.2KΩ$ H304 H7307322A Transistor, 2SC732 B or G R365 R70510114 100Ω H305 H7307322A Transistor, 2SC732 B or G R366 R70510114 100Ω H306 H7104942A Transistor, 2SA494 G or Y R368 R70527414 270KΩ H308 H7308281D Transistor, 2SC828S R369 R70515314 15KΩ H309 H7308281D Transistor, 2SC828S				1 1		1		0.04µF +80%, -20	1%
R358 RT0510114 100Ω R359 RT0527314 27KΩ R360 RT0533314 33KΩ R361 RT0522414 220KΩ R362 RA0104018 Trimming, 10KΩ (B) R363 RA0103025 Trimming, 10KΩ (B) R364 RT0522214 2.2KΩ R365 RT0510114 100Ω R366 RT0510314 10KΩ R367 RT0510114 100Ω R368 RT0527414 270KΩ R369 RT0515314 15KΩ	1					1	1	0.04µF +80%, -20	1%
R359 RT0527314 $27KΩ$ $C341$ DK1840302 Ceramic, $0.04μF + 80\%, -20\%$ R360 RT0533314 $33KΩ$ SEMICONDUCTORS R361 RT0522414 $220KΩ$ H301 HF200342C FET, 2SK34C, D Transistor, 2SC828S R362 RA0104018 Trimming, 10KΩ (B) H302 HT308281D Transistor, 2SC828S R363 RA0103025 Trimming, 10KΩ (B) H303 HT308281D Transistor, 2SC828S R364 RT0522214 2.2KΩ H304 HT307322A Transistor, 2SC732 B or G R365 RT0510114 100Ω H305 HT307322A Transistor, 2SC732 B or G R366 RT0510314 10KΩ H306 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 270KΩ H308 HT308281D Transistor, 2SC828S R369 RT0515314 15KΩ H309 HT308281D Transistor, 2SC828S			l .				,		
R360 RT0533314 33KΩ SEMICONDUCTORS R361 RT0522414 220KΩ H301 HF200342C FET, 2SK34C, D R362 RA0104018 Trimming, 10KΩ (B) H302 HT308281D Transistor, 2SC828S R363 RA0103025 Trimming, 10KΩ (B) H303 HT308281D Transistor, 2SC828S R364 RT0522214 2.2KΩ H304 HT307322A Transistor, 2SC732 B or G R365 RT0510114 100Ω H305 HT307322A Transistor, 2SC732 B or G R366 RT0510314 10KΩ H306 HT104942A Transistor, 2SA494 G or Y R367 RT0510114 100Ω H307 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 270KΩ H308 HT308281D Transistor, 2SC828S R369 RT0515314 15KΩ H309 HT308281D Transistor, 2SC828S			1	ll c	341	DK1840302	Ceramic,	0.04µF +80%, -20	1%
R361 R70522414 220KΩ H301 HF200342C FET, 2SK34C, D Transistor, 2SC828S Trimming, $10KΩ$ (B) H302 HT308281D Transistor, 2SC828S Transistor, 2SC828S Transistor, 2SC828S Transistor, 2SC828S Transistor, 2SC828S Transistor, 2SC732 B or G R364 R70522214 2.2KΩ H304 HT307322A Transistor, 2SC732 B or G R365 R70510114 $100Ω$ H305 HT307322A Transistor, 2SC732 B or G Transistor, 2SC732 B or G R70510114 $100Ω$ H306 HT104942A Transistor, 2SC494 G or Y R368 R70527414 270KΩ H308 HT308281D Transistor, 2SC828S R369 R70515314 $15KΩ$ H309 HT308281D Transistor, 2SC828S Transisto			l .	11					
R361 RA0104018 Trimming, 100KΩ (B) H302 HT308281D Transistor, 2SC828S R363 RA0103025 Trimming, 10KΩ (B) H303 HT308281D Transistor, 2SC828S R364 RT0522214 2.2KΩ H304 HT307322A Transistor, 2SC732 B or G R365 RT0510114 100Ω H305 HT307322A Transistor, 2SC732 B or G R366 RT0510314 10KΩ H306 HT104942A Transistor, 2SA494 G or Y R367 RT0510114 100Ω H307 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 270KΩ H308 HT308281D Transistor, 2SC828S R369 RT0515314 15KΩ H309 HT308281D Transistor, 2SC828S	43	60 110000014	35.112	11			SEMICONE	OUCTORS	
R362 RA0104018 Trimming, 100KΩ (B) H302 HT308281D Transistor, 2SC828S Transistor, 2SC828S R363 RA0103025 Trimming, 10KΩ (B) H303 HT308281D Transistor, 2SC828S R364 RT0522214 2.2KΩ H304 HT307322A Transistor, 2SC732 B or G R365 RT0510114 100Ω H305 HT307322A Transistor, 2SC732 B or G R366 RT0510314 10KΩ H306 HT104942A Transistor, 2SA494 G or Y R367 RT0510114 100Ω H307 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 270KΩ H308 HT308281D Transistor, 2SC828S R369 RT0515314 15KΩ H309 HT308281D Transistor, 2SC828S	02	61 RT0522414	220ΚΩ	н	301	HF200342C	1		
R363 RA0103025 Trimming, 10KΩ (B) H303 HT308281D Transistor, 2SC828S R364 RT0522214 2.2KΩ H304 HT307322A Transistor, 2SC732 B or G R365 RT0510114 100Ω H305 HT307322A Transistor, 2SC732 B or G R366 RT0510314 10KΩ H306 HT104942A Transistor, 2SA494 G or Y R367 RT0510114 100Ω H307 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 270KΩ H308 HT308281D Transistor, 2SC828S R369 RT0515314 15KΩ H309 HT308281D Transistor, 2SC828S Tansistor, 2SC828S Transistor, 2SC828S Transistor, 2SC828S Transistor, 2SC828S				1 1		1	1		
R364 RT0522214 2.2KΩ H304 HT307322A Transistor, 2SC732 B or G R365 RT0510114 100Ω H305 HT307322A Transistor, 2SC732 B or G R366 RT0510314 $10K\Omega$ H306 HT104942A Transistor, 2SA494 G or Y R367 RT0510114 100Ω H307 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 $270K\Omega$ H308 HT308281D Transistor, 2SC828S R369 RT0515314 $15K\Omega$ H309 HT308281D Transistor, 2SC828S Table 10 Transistor, 2SC828S Transistor, 2SC828S Transistor, 2SC828S				1 1				2SC828S	
R365 RT0510114 100Ω H305 HT307322A Transistor, 2SC732 B or G R366 RT0510314 $10KΩ$ H306 HT104942A Transistor, 2SA494 G or Y R367 RT0510114 $100Ω$ H307 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 $270KΩ$ H308 HT308281D Transistor, 2SC828S R369 RT0515314 $15KΩ$ H309 HT308281D Transistor, 2SC828S			,				Transistor,		
R366 RT051 0314 10 KΩ H306 HT104942A Transistor, 2SA494 G or Y Tr			i .	1 1		l .	Transistor,	2SC732 B or G	
R367 RT0510114 100Ω H307 HT104942A Transistor, 2SA494 G or Y R368 RT0527414 270KΩ H308 HT308281D Transistor, 2SC828S R369 RT0515314 15KΩ H309 H7308281D Transistor, 2SC828S Transistor, 2SC828S Transistor, 2SC828S Transistor, 2SC828S			I .	1 1		HT104942A	Transistor,		
R368 RT0527414 270KΩ H308 HT308281D Transistor, 2SC828S Transisto				1 1		HT104942A	Transistor,		
R369 RT0515314 15KΩ H309 HT308281D Transistor, 2SC828S			1	1 1		HT308281D			
1 1040 UT000001D Translator 2000200			1	н	309				
		'		н	310	HT308281D	Transistor,	2SC828S	
				I		L	J		

	MAAD ANTZ	
REF. DESIG.	MARANTZ PART NO.	DESCRIPTION
Н311	HT308281D	Transistor, 2SC828S
H312	HF200300A	FET 2SK30A
H313	HT308281D	Transistor, 2SC828S
H314	HT308281D	Transistor, 2SC828S
H315	HT308281D	Transistor, 2SC828S
H316	HT308281D	Transistor, 2SC828S
H317	HT308281D	Transistor, 2SC828S
H318	HD1000105	Diode, 1N60
H319	HD1000105	Diode, 1N60
H320	HD2001105	Diode, 1S1555
H321	HC1000401	IC, IC. HA1156
		COILS
L301	LS1029004	MPX Coil, 56mH
L302	LS1029004	MPX Coil, 56mH
L302	LS1029005	MPX Coil, 43mH
1	LS1029005	MPX Coil, 43mH
L304 L305	LC2105001	Choke Coil, 1mH
2303	20210001	
J301		MISCELLANEOUS
}	YP1000113	Plug
J317	11.10001.10	
3317		
J322	YP1000113	Plug
D400	YD2884005	P.W. Board, Power Supply
P400	ZZ2884005	P.W. Board Ass'y
	222864005	F.W. Board Ass y
		RESISTORS
2404	DC1022212	3.3 K $\Omega \pm 10\%$, ½W
R401	RC1033212	$12\Omega \pm 10\%$, ½W
R402	RC1012012	$270\Omega \pm 10\%$, ½W
R403	RC1027112	
R404	RC1015312	10.111
R405	RC1033312	
R406	RC1012012	120
R407	RC1015212	
R408	GS1010105	$100\Omega \pm 10\%$, 5W
R409	RC1047112	$470\Omega \pm 10\%$, ½W.
R413	RT0539114	$390\Omega \pm 5\%$, %W
R414	RT0539114	$390\Omega \pm 5\%$, ¼W
R415	RT0510514	$1M\Omega \pm 5\%$, ^{1}W
R416	RT0510514	$1M\Omega \pm 5\%$, ^{1}W
R417	RT0510514	$1M\Omega \pm 5\%$, $\%W$
R418	RT0510514	$1M\Omega \pm 5\%$, ^{1}W
R419	RT0515114	$150\Omega \pm 5\%$, ¼W
R420	RT0515114	$150\Omega \pm 5\%$, ¼W
R421	RT0510314	$10K\Omega \pm 5\%$, ^{1}W
R422	RT0510314	$10K\Omega \pm 5\%$, ^{1}W
R423	RT0510414	100 K $\Omega \pm 5\%$, $\%$ W
R424	RT0510414	100KΩ ± 5%, ¼W
11727	1,1,00,10,114	
1	DK4040354	CAPACITORS Ceramic, 0.01µF +100%
C401	DK1810351	
C402	DK1810351	- · · · · · · · · · · · · · · · · · ·
C403	EA3370509	
C404	EA3370509	Electroly, 330µF, 50V
C405	EA1070259	Electroly, 100µF, 25V
C406	EA1070259	Electroly, 100μF, 25V
C407	EA4760509	Electroly, 47µF, 50V
C408	EA4760509	Electroly, 47µF, 50V
C409	EV1050352	Electroly, 1μF, 35V
C410	EV1050352	Electroly, 1μF, 35V
C411	EV1050352	Electroly, 1μF, 35V
C411 C412	EV1050352	Electroly, 1μ F, 35V
U412	LV 1000002	

ſ	REF. DESIG.	MARANTZ PART NO.	DESCRIPTION
Ī	C413	EA1070359	Electroly, 100μF, 35V
		_	SEMICONDUCTORS
١	H401	HT313441E	Transistor, 2SC1344 (E)
	H402	HT313441E	Transistor, 2SC1344 (E)
١	H403	HT312132A	Transistor, 2SC1213A (B), (C)
- 1	H404	HD3003209	Diode, CZ-142
	H405	HD2000501	Diode, W06B
	H406	HD2000501	Diode, W06B
- 1	H407	HT403154A	Transistor, 2SD315 (C, D, E, F)
	H407	1114031347	11411313101, 200010 (0, 0, 2, 1, 1)
	T401	273026702	MISCELLANEOUS Heat Sink
	J401		
	3 4 01 }	YP1000113	Plug
		11 1000113	riug
-	J413		
ı	0400	200446050	Brankst K
	0403	288416050	Bracket K
	0422	288426251	Pulley K
	0506	288416003	Bracket
	0507	288416004	Bracket
	0513	288420101	Partitioner
	0520	288410901	Shield
	0703	51100306A	B.H.M. Screw x 4
	0704	51100306A	B.H.M. Screw x 2
	0706	51102606A	B.H.M. Screw x 2
İ	0707	51042606S	F.H.M. Screw x 2
1			
	0711	51042606S	F.H.M. Screw x 4
	0712	53112603E	Hexagon Nut x 2
ı	0713	54022601E	Flat Washer P x 2
	07.10	010220012	
	0726	51100306A	B.H.M. Screw x 2
	0,20	011000001	
ļ	0728	51100306A	B.H.M. Screw × 2
l	0720	3110000071	D.T.I.M. GGIGW
	0730	51100406A	B.H.M. Screw × 6
1		51570306B	P.H. Tapt Screw × 2
ı	0731	515703000	r.n. Tapt Sciew X 2
١	1122	200210001	Shield
ļ	1122	288210901	Silieid
1	0620	257710602	Bearing
1	0628	141511801	_
	0629		Spacer F.H.M. Screw × 2
1	0631	51040306A	F.H.M. Screw × 2
	0400	200405150	Guida K
1	0409	288405150	Guide K
1	0412	257726201	Pulley
1	0412	257726201	R.G. Ring E
	0413	64002400R	1
	0715	51042604A	F.H.M. Screw x 2
	0445	200420250	Bullov K
	0415	288426250	Pulley K
1	0544	201010107	Support
	0514	281810107	Support
	0500	200427402	Reflector
1	0502	288427402	
1	0503	288427103	Holder
		V.100000010	Carlos
1	J010	YJ0800013	Socket
1	J011	YJ0800013	Socket
1	M003	IN1008007	Lamp
	M004	IN1008007	Lamp
1	0708	51570306B	P.H. Tapt Screw x 2
	L	L	L

ESIG.	MARANTZ PART NO.	DESCRIPTION
0709	51100306A	B.H.M. Screw
M001 M002	IM1104202 IM1104210	DC Meter, Tuning DC Meter, Signal
	200427401	, •
0429 0430	288427401 288427101	Reflector Holder
0431	288427102	Holder
0717 0718	51570306B 51100306A	P.H. Tapt Screw x 3 B.H.M. Screw x 2
0720	51480306A	B.H.M. Screw x 2
0722	51570306B	P.H. Tapt Screw x 2
PZ01	YD2884003	P.W. Board, Dial Lamp
. 20.	ZZ2884003	P.W. Board Ass'y
14701	IN1000007	MISCELLANEOUS Lamp. Dial Illumi.
MZ01 MZ02	IN1008007 IN1008007	Lamp, Dial Illumi. Lamp, Dial Illumi.
MZ03	IN1008007	Lamp, Dial Illumi.
MZ04 MZ05	IN1008007 IN1008007	Lamp, Dial Illumi. Lamp, Dial Illumi.
	1141000007	Early, Dia manif.
JZ01 }	YP1000113	Plug
JZ04		
JZ05		
} JZ14	YJ0800017	Socket
JZ 14		
PY01	YD2884004	P.W. Board, Selector Lamp
	ZZ2884004	P.W. Board Ass'y
		MISCELLANEOUS
MY01 MY02	IN1012011 IN1006301	Lamp, Stereo Lamp, Muting
MY03	IN1006301	Lamp, FM
MY04	IN1006301	Lamp, AM
MY05	IN1006301 IN1006301	Lamp, Hi Blend Lamp, Mono
MY06	110100001	Lamp, Mono
JY01 {	YP1000113	Plug
J, 09		
R005	RM0104008	Variable Resist., 100KB x 2, Output
R004	RK0203029	Variable Resist., 20KB, Muting
PS01	YD2884001	P.W. Board, Selector Push Switch
roui	ZZ2884001	P.W. Board Ass'y
		MISCELLANEOUS
RS01	RT0556114	Resistor, $560\Omega \pm 5\%$, $\%$ W
RS02 RS03	RT0556114 RC1002212	Resistor, $560\Omega \pm 5\%$, $\%$ W Resistor, $2.2\Omega \pm 5\%$, $\%$ W
RS05	RC1002212	$\begin{array}{lllll} \text{Resistor,} & 560\Omega \pm 5\%, & \%\text{W} \\ \text{Resistor,} & 560\Omega \pm 5\%, & \%\text{W} \\ \text{Resistor,} & 2.2\Omega \pm 5\%, & \%\text{W} \\ \text{Resistor,} & 2.2\Omega \pm 10\%, & \%\text{W} \end{array}$
CS01	EA3360109	Electroly Cap., 33μF, 10V

	REF. DESIG.	MARANTZ PART NO.	DESCRIPTION
	PT01	YD2884002 ZZ2884002	P.W. Board, Mono Push Switch P.W. Board Ass'y
			MISCELLANEOUS
	RT01 RT02	RC1002212 RC1002212	Resistor, $2.2\Omega \pm 10\%$, ½W Resistor, $2.2\Omega \pm 10\%$, ½W
l	CT01	DF1622301	Film Cap., 0.022μF ± 10%
	ST01	SP0402006	Push Switch, HIBLEND-MONO
	S002 S002	SP0201010 SP0101010	Push Switch Push Switch, For CANADA
	0819	145525903	Bush x 2
	0829 0830	257816010 257816011	Bracket Bracket
	1307	62031650W	Lug x 2
	J001	YT0304002	Terminal, Ant.
	J007	YJ0800012	Socket, Fuse Holder
	J009	YT0101003	Terminal, Ground
	0903 0904	51100308S 53110303E	B.H.M. Screw x 2 Hexagon Nut x 2
	0906 0907	51100308S 53110303E	B.H.M. Screw x 4 Hexagon Nut x 4
	0916 0917	51100306S 62031650W	B.H.M. Screw x 2 Lug
	0920	51100306S	B.H.M. Screw x 4
	0934 0935	51100306S 54040302N	B.H.M. Screw x 3 Spring Washer x 3
	0924 0926	62041760W 54050400R	Lug T.L. Washer OR
	L002	BF1040001	Balun Coil
	G001 R009	BF1040001 GT0522512	Printed Compo. Resistor, $2.2M\Omega \pm 5\%$, ½W
	W001	YC0240010	AC Cord
	0811	257816052	Bracket K
	0816 0929 0930 0931 0932 0933 L001 R001 R002 R003 S001 J004 J005 1134	281927103 51100310S 53110303E 51100308S 53110303E 54050300R LF1120023 RC1068012 RC1068012 RC1008212 SS0202017 YT0201006 YT0202007 138200503	Holder B.H.M. Screw x 2 Hexagon Nut x 2 B.H.M. Screw x 2 Hexagon Nut x 2 T.L. Washer OR x 2 Ant. Coil, AM Resistor, $680\Omega\pm10\%$, ½W Resistor, $680\Omega\pm10\%$, ½W Resistor, $8.2\Omega\pm10\%$, ½W Slide Switch, FM Ant. Att. Terminal, Quadradial Output Clamper x 5

main reamiz

055				
REF. DESIG.	MARANTZ PART NO.	DESCRIPTION		
R008	RC1039012	Resistor, $39\Omega \pm 10\%$, ½W		
C001 L004	DK1710301 LC1332002	Ceramic Cap., $0.01 \mu F \pm 20\%$ Choke Coil		
0510	288430201	Dial		
0434 W002	288410701 YX2884001	Sheet Wire Materials		
W002	YW2884001	Wire Materials Wire Materials		
0126	275905701	Leg x 4		
0313	51490410S	B.H.M. Screw FS x 4		
1103	285210550	Chassis K		
1114	282610102	Support		
1124	380210102	Support x 2		
1125	288710903	Shield		
1127	288410903	Shield		
1128	288410904	Shield		
1133 3536	273025901 138200503	Bush x 3 Clamper x 3		
3537	62031650W	Lug x 2		
1203	51570306B	P.H. Tapt Screw x 2		
1203	51100306E	P.H.M. Screw x 4		
1206	51570306B	P.H. Tapt Screw x 4		
1207	51100306S	B.H.M. Screw x 4		
1209	51570408B	P.H. Tapt Screw x 2		
1210	54020401E	Flat Washer P x 2		
1211	54040402N	Spring Washer x 2		
1218	51100306S	B.H.M. Screw x 5		
1219	51100306S	B.H.M. Screw x 2		
1220	51570306B	P.H. Tapt Screw x 4		
1221	51100306E	P.H. Tapt Screw x 5		
1222 1223	51100306S 288405302	P.H. Tapt Screw x 3 Cap x 3		
1225	200403302	Cap X3		
1225	59030805P	Fiver Washer		
1226	59030810P	Fiver Washer x 4		
1228	51570306B	P.H. Tapt Screw x 4		
1229	51100306S	B.H.M. Screw x 2		
1230	54040302N	Spring Washer x 2		
1 231	51570306B	P.H. Tapt Screw x 4		
1302	51570306B	P.H. Tapt Screw x 5		
1303	51570306B	P.H. Tapt Screw x 7		
1305	54050300R	T.L. Washer OR x 5		
1311	54020301S	Flat Washer		
R007	RK0503009	Variable Resist., 50KΩ (B)		
L005	TS1600905	Power Transf., 120V		
F001	FS1005009	Fuse, 250V, 0.5A, UL		
O 110	281815402	Knob		
0111	281815401	Knob x 5		
	282815401	Knob x 2		
0112		1		

REF. DESIG.	MARANTZ PART NO.	DESCRIPTION
0117	257711803	Spacer x 4
0121	282625702	Lid
0130	145512001	Insulator
0132	288406450	Case K
0202 0203	288426501 288426502	Indicator Indicator, For CANADA
0919	51100306S	B.H.M. Screw x 2
0211 0212	257886101 257886102	Label, UL Caution Label, Do not Remove Cover.
0213 0214	257886103 250626506	Label, See marking Indicator, Do not use as
0219 0220	282186101 282186102	Label, LL24902, For CANADA Label, Fuse Caution, For CANADA
0231 0232	951022101 285226508	Label, For CANADA Indicator, For CANADA
0303	52017039J	H. Head Bolt x 4
0305	51100406S	B.H.M. Screw x 8
0309	51480406S	B.H.M. Screw F x 4
0317 0318	52010420A 54080400R	H. Head Bolt x 4, For CANADA T.L. Washer R R x 4, For CANADA
0427	282626901	Protector
0516 0517 0518	281912004 288400701 287105302	Insulator Strip Cover x 2
0521	288411801	Spacer
0534	56382540G	Eyelet
0607 0608	285011202 54040402N	Shaft Spring Washer
0616	281810650	Bearing K
0620 0621 0622	51640410D 54040402N 53110403E	Set Screw C.R. Spring Washer Hexagon Nut
0624 0625	51100306A 54050300R	B.H.M. Screw x 2 T.L. Washer OR x 2
0724	51100306S	B.H.M. Screw x 2
1522 1523	952281501 952301512	Serial NO Card x 4 Serial NO Card x 4, For CANADA
1402 1409 1417 1418 1419 1420 1423	288485101 288485601 281885104 288785108 288785109 282685107 257785450	Instructions Schematic Diagram Instructions Instructions Instructions, For CANADA Instructions Guarantee Card K

REF.	MARANTZ		_	
DESIG.	PART NO.	DESCRIPTION		
1502 1503 1505 1506 1508 1510 1512 1513 1514 1517	288480103 288480104 288480102 288480112 288480301 285280303 901433533 901453535 901302501 102980401	Packing Case Packing Case Packing Case, Packing Case, Partitioner x 2 Partitioner x 2, Polyethylen Bag Polyethylen Bag, Polyethylen Bag Sleeve	For CANADA For CANADA For CANADA For CANADA × 2	
1519 1520	273182101 281905601	Silicagel x 2		
1520 1513 1533		Buffer Ext. Antenna, Connective Cord	FM	
	-			

8. TECHNICAL SPECIFICATIONS

FM SECTION:

IHFM Usable IHFM Select Capture Rati Image Reject Signal to No Signal to No Total Harmo Total Harmo Frequency F	guency Range 88—108MHz e Sensitivity 2.3 µV tivity 60 dB io 1.6 dB tion Ratio at 106MHz 70 dB sise Ratio (Mono) 70 dB sise Ratio (Stereo) 60 dB onic Distortion (Mono) 0.15% onic Distortion (Stereo) 0.3% Response (ref. 75µ sec. de-emphasis) ±1dB, 30Hz—15KHz ration at 1KHz 42dB	
AM SECTIO	DN:	
Usable Sensi Selectivity Image Reject Signal to Not Frequency for Total Harmon	quency Range 540—1605KHz itivity 20µV 26dB ction Ratio 70dB bise Ratio 46dB Response, —3dB down 50Hz—4KHz onic Distortion 1%	; ; ; ;
GENERAL:		
Power Requ	uirements · · · · · · · · 120V AC	j Z
Power Cons Dimensions	sumption 25 Watts Panel Width 15-3/8 Panel Height 5-3/4 Depth 11-13/16	3 4 6
Weight	Unit alone	

^{*}These specifications and exterior designs may be changed for improvement without advance notice.